# UNISONIC TECHNOLOGIES CO., LTD

UT2301Z **Power MOSFET** 

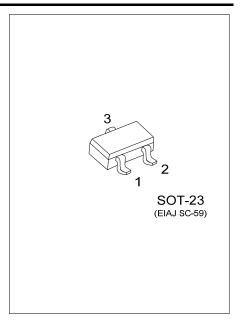
# -2.8A, -20V P-CHANNEL **ENHANCEMENT MODE POWER MOSFET**

#### **DESCRIPTION**

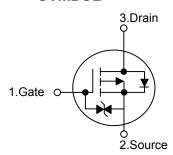
The UTC UT2301Z is a P-channel enhancement mode power MOSFET with fast switching speed, low on-resistance and favorable stabilization. It can be used in commercial and industrial surface mount applications and suited for low voltage applications such as DC/DC converters.

#### **FEATURES**

- \* Very High Density Cell Design for Low On-Resistance
- \* Very Good Thermal and Electrical Capabilities



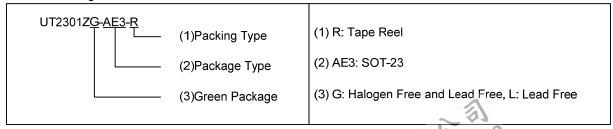
#### **SYMBOL**



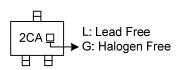
#### ORDERING INFORMATION

Ordering Number		Doolsone	Pin Assignment			Dooking	
Lead Free	Halogen Free	Package	1	2	3	Packing	
UT2301ZL-AE3-R	UT2301ZG-AE3-R	SOT-23	G	S	D	Tape Reel	

Note: Pin Assignment: G: Gate S: Source D: Drain



#### **MARKING**



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# **ABSOLUTE MAXIMUM RATINGS** (T<sub>A</sub> = 25°C, unless otherwise specified)

PARAMETER	SYMBOL	RATING	UNITS
Drain-Source Voltage	$V_{DS}$	-20	V
Gate-Source Voltage	$V_{GS}$	±8	V
Continuous Drain Current	I <sub>D</sub>	-2.8	Α
Pulsed Drain Current (Note 2, 3)	I <sub>DM</sub>	-10	Α
Total Power Dissipation (Note 4)	P <sub>D</sub>	1.25	W
Junction Temperature	TJ	+150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~ <b>+</b> 150	°C

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

- 2. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 3. Pulse width  $\leq 300 \mu s$ , duty cycle  $\leq 2 \%$ .
- 4. Surface mounted on 1 in 2 copper pad of FR4 board.

## THERMAL CHARACTERISTICS

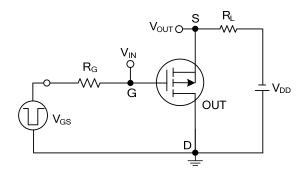
PARAMETER	SYMBOL	RATING	UNIT
Junction to Ambient	$\theta_{JA}$	100	°C/W

Note: Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

### **ELECTRICAL CHARACTERISTICS** (I<sub>D</sub>=-2.3A , T<sub>A</sub>=25°C, unless otherwise specified)

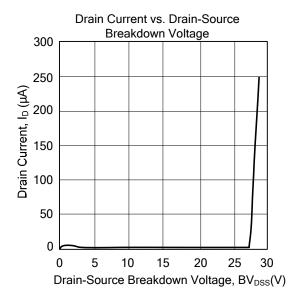
PARAMETER	SYMBOL	TEST CONDITIONS MIN		TYP	MAX	UNITS	
OFF CHARACTERISTICS							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V, I <sub>D</sub> =-250uA -2				V	
Zero Gate Voltage Drain Current	I <sub>DSS</sub>	V <sub>DS</sub> =-16V, V <sub>GS</sub> =0V			-1.0	μΑ	
Gate-Source Leakage Current	I <sub>GSS</sub>	$V_{GS}=\pm 8V$ , $V_{DS}=0V$			±5	μΑ	
ON CHARACTERISTICS							
Gate Threshold Voltage	$V_{GS(TH)}$	$V_{DS}=V_{GS}$ , $I_D=-250uA$	-0.45			V	
Static Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =-4.5V, I <sub>D</sub> =-2.8A		95	130	mΩ	
Static Drain-Source On-State Resistance		V <sub>GS</sub> =-2.5V, I <sub>D</sub> =-2.0A		122	190	mΩ	
On-State Drain Current	I <sub>D(ON)</sub>	V <sub>DS</sub> =-5 V, V <sub>GS</sub> =-10V				Α	
Forward Tran conductance	<b>g</b> FS	V <sub>DS</sub> =-5 V, I <sub>D</sub> =-2.8A		6.5		S	
DYNAMIC CHARACTERISTICS							
Input Capacitance	C <sub>ISS</sub>			447		pF	
Output Capacitance	Coss	$V_{GS}$ =0V, $V_{DS}$ =-6V, f=1.0MHz		127		pF	
Reverse Transfer Capacitance	C <sub>RSS</sub>			80		pF	
SWITCHING CHARACTERISTICS							
Total Gate Charge (Note)	$Q_G$	\\ - 6\\ \\ - 4.5\\		5.4	10	nC	
Gate-Source Charge	$Q_GS$	V <sub>DS</sub> =-6V, V <sub>GS</sub> =-4.5V,		8.0		nC	
Gate-Drain Charge	$Q_GD$	ID2.0A		1.1		nC	
Turn-ON Delay Time (Note)	t <sub>D(ON)</sub>			5	25	ns	
Turn-ON Rise Time	t <sub>R</sub>	$V_{DD}$ =-6V, $V_{GEN}$ =-4.5V, $I_{D}$ =-1A, $R_{G}$ =6 $\Omega$ , $R_{L}$ =6 $\Omega$		19	60	ns	
Turn-OFF Delay Time	t <sub>D(OFF)</sub>			95	110	ns	
Turn-OFF Fall Time	t <sub>F</sub>			65	80	ns	
SOURCE- DRAIN DIODE RATINGS AND CH	ARACTERI	STICS	37				
Maximum Diode Forward Current	Is	18. V 200			-1.6	Α	
Diode Forward Voltage (Note)	$V_{SD}$	I <sub>S</sub> =-1.6 A, V <sub>GS</sub> =0 V	).	-0.8	-1.2	V	
Diode Forward Voltage (Note)  Notes: Pulse width ≤300μs, Duty Cycle ≤2%  UNISONIC TECHNOLOGIES CO., LTD  www.unisonic.com.tw  2 of 4							
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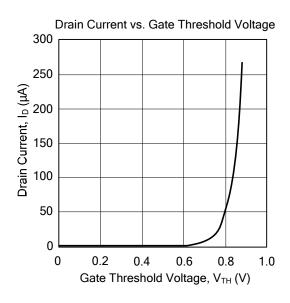
# **SWITCHING TEST CIRCUIT**

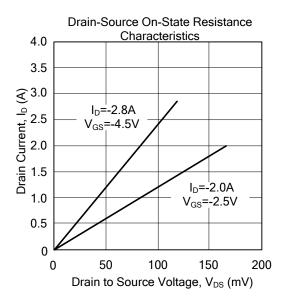


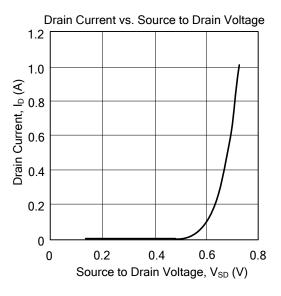


#### ■ TYPITAL CHARACTERISTICS









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